

**DR. BABASAHEB AMBEDKAR TECHNOLOGICAL UNIVERSITY**  
**LONERE – RAIGAD -402 103**  
**Winter End Semester Examination: Dec. 2019**

**Branch: B. Tech.**

**Sem.:- I/II**

**Subject:- Basic Electronics Engineering (EXE105/EXE205) Marks: 60**

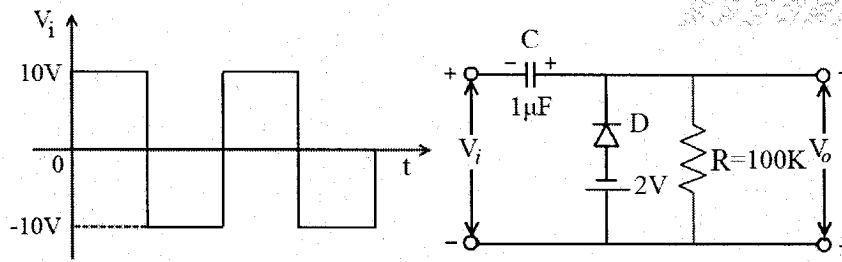
**Date:- 06/12/2019**

**Time:- 3 Hr.**

**Instructions:-**

1. Attempt any *Five* questions.
2. All questions carry equal marks.
3. Illustrate your answer with neat sketches, diagrams etc. wherever necessary.
4. Necessary data is given in the respective questions. If such data is not given, it means that the knowledge of that component is a part of examination.
5. If some part or parameter is noticed to be missing, you may appropriately assume and state it clearly in the answer-book.

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- Q.1. A] Describe essential features of the following bonds: 06
- (a) Ionic bond
  - (b) Covalent bond
  - (c) Metallic bond
- B] Explain the classification of materials with electrical engineering point of view. 06
- Q.2. Attempt any *two* of the followings:
- A] How does the Fermi level changes with increasing temperature in the extrinsic semiconductors (*n*- type and *p* -type)? Sketch the energy level diagram. 06
- B] What is Hall effect? Calculate Hall voltage, Hall coefficient and Hall angle. 06
- C] Find the built-in voltage for a *Si* P-N junction with  $N_A = 10^{15} \text{ cm}^{-3}$  and  $N_D = 10^{17} \text{ cm}^{-3}$  at room temperature with  $n_i = 10^{10} \text{ cm}^{-3}$ . 06
- Q.3 A] Sketch  $V_o$  for the circuit and the input shown. *D* is a silicone diode with cut in voltage  $V_f = 0.6V$ . 06



- B] Write a note on depletion layer capacitance and diffusion capacitance. 06
- Q.4 Define transistor biasing. List and explain different transistor biasing techniques with suitable diagram and expressions. 12
- Q.5. Attempt any *two* of the followings:
- A] Describe the working of center tap full wave rectifier with neat diagram and waveforms. Explain: Peak inverse voltage, ripple factor and efficiency with respect to a center tap full wave rectifier. 06
- B] Explain different types of resistors in detail. What is the color code for 1KΩ resistor? 06
- C] Describe construction and working of a LVDT. State any two advantages and disadvantages of LVDT. 06
- Q.6 A] Do as directed: 06
- Obtain 2's complement of 10111011
  - Add  $(AF1.B3)_H + (FFF.E)_H$
  - Determine the floating point representation of  $(-142)_{10}$  using IEEE single precision format.
- B] Explain AND, OR, NAND, NOR, Ex-OR, Ex-NOR logic gates with their logic diagram and truth table. 06

\*\*\*\*\*PAPER END\*\*\*\*\*